MOSFETs Silicon Carbide N-Channel MOS

TW015Z120C

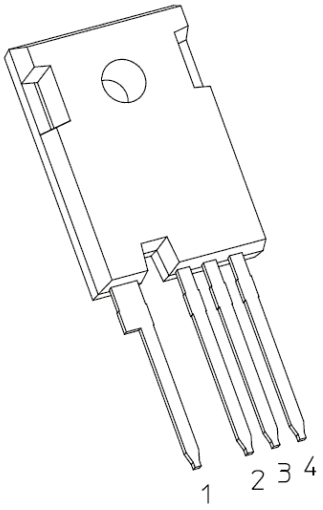
1. Applications

- Switching Voltage Regulators

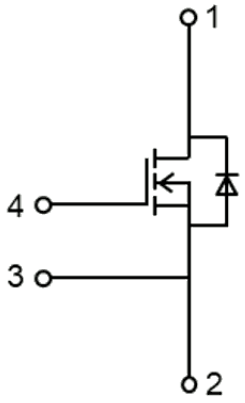
2. Features

(1) Chip design of 3rd generation (Built-in SiC schottky barrier diode)
(2) Low diode forward voltage: V_{DSF} = -1.35 V (typ.)
(3) High voltage: V_{DSS} = 1200 V
(4) Low drain-source on-resistance: $R_{DS(ON)}$ = 15 mΩ (typ.)
(5) Less susceptible to malfunction due to high threshold voltage: V_{th} = 3.0 to 5.0 V (V_{DS} = 10 V, I_D = 11.7 mA)
(6) Recommended gate - source drive voltage: V_{GS_on} = 18 V, V_{GS_off} = 0 V
(7) Enhancement mode.

3. Packaging and Internal Circuit



TO-247-4L(X)



1. Drain (heatsink)
2. Source 1
3. Source 2
4. Gate

Notice: Only use source 2 pin for gate input signal return. Please make sure that the main current flows into the source 1 pin.

Start of commercial production
2023-06

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4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	1200	V
Gate-source voltage			V_{GSS}	+25/-10	
Drain current (DC)	(T_c = 25 °C)	(Note 1)	I_D	100	A
Drain current (DC)	(T_c = 100°C)	(Note 1)	I_D	81	
Drain current (pulsed)	(T_c = 25 °C)	(Note 1)	I_{DP}	336	
Drain current (pulsed)	(T_c = 100°C)	(Note 1)	I_{DP}	235	
Power dissipation	(T_c = 25°C)		P_D	431	W
Channel temperature			T_{ch}	175	°C
Storage temperature			T_{stg}	-55 to 175	
Mounting torque			TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	0.348	°C/W
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	50	

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.
It should be used for switching applications.

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6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

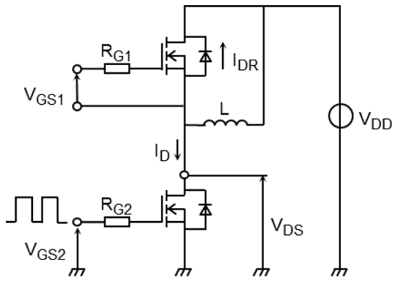
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	V_{GS} = +25/-10 V, V_{DS} = 0 V	—	—	±0.1	μA
Drain cut-off current	I_{DSS}	V_{DS} = 1200 V, V_{GS} = 0 V	—	3	38	
		T_a = 150 °C, V_{DS} = 1200 V, V_{GS} = 0 V	—	17	—	
Drain-source breakdown voltage	$V_{(BR)DSS}$	I_D = 4 mA, V_{GS} = 0 V	1200	—	—	V
Gate threshold voltage (Note 2)	V_{th}	V_{DS} = 10 V, I_D = 11.7 mA	3.0	—	5.0	
Drain-source on-resistance	$R_{DS(ON)}$	V_{GS} = 18 V, I_D = 50 A	—	15	21	mΩ
		T_a = 150 °C, V_{GS} = 18 V, I_D = 50 A	—	24	—	

Note 2: Please be sure to apply I_{GSS} (V_{GS} = 25 V) before the V_{th} test.

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6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = 800 V, V_{GS} = 0 V, f = 100 kHz	—	6000	—	pF
Reverse transfer capacitance	C_{rss}		—	7	—	
Output capacitance	C_{oss}		—	289	—	
Effective output capacitance (energy related)	$C_{o(er)}$		—	331	—	
Effective output capacitance (time related)	$C_{o(tr)}$		—	496	—	
Output charge	Q_{oss}		—	397	—	nC
C_{oss} stored energy	E_{oss}		—	106	—	μJ
Gate resistance	r_g	V_{DS} = OPEN, f = 1 MHz	—	1.1	—	Ω
Turn-on delay time	$t_{d(on)}$	See Figure 6.2.1	—	40	—	ns
Switching time (rise time)	t_r		—	18	—	
Turn-off delay time	$t_{d(off)}$		—	69	—	
Switching time (fall time)	t_f		—	24	—	
Turn-on switching loss	E_{on}		—	1079	—	μJ
Turn-off switching loss	E_{off}		—	420	—	



V_{GS1} = 0 V
R_{G1} = 0 Ω
V_{GS2} = 0 V / 18 V (pulsed)
R_{G2} = 4.7 Ω
V_{DD} ≈ 800 V
I_D = 50 A
L = 100 μH

Fig. 6.2.1 Switching Time Test Circuit

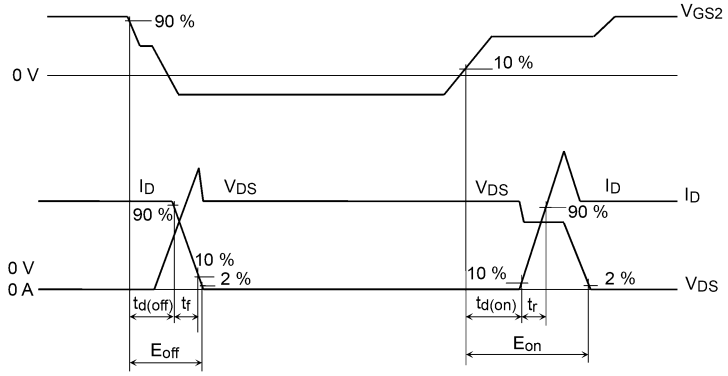


Fig. 6.2.2 Timing Diagrams

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx$ 800 V, V_{GS} = 18 V, I_D = 50 A	—	158	—	nC
Gate-source charge 1	Q_{gs1}		—	56	—	
Gate-drain charge	Q_{gd}		—	23	—	

6.4. Source · Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (DC) (Note 3)	I_{DR}	T_c = 25 °C, V_{GS} = -5 V	—	—	92	A
		T_c = 100 °C, V_{GS} = -5 V	—	—	62	
		T_c = 25 °C, V_{GS} = 18 V	—	—	100	
		T_c = 100 °C, V_{GS} = 18 V	—	—	81	
Reverse drain current (pulsed) (Note 3)	I_{DRP}	T_c = 25 °C, V_{GS} = -5 V	—	—	336	
		T_c = 100 °C, V_{GS} = -5 V	—	—	115	
		T_c = 25 °C, V_{GS} = 18 V	—	—	336	
		T_c = 100 °C, V_{GS} = 18 V	—	—	235	
Diode forward voltage	V_{DSF}	I_{DR} = 31 A, V_{GS} = -5 V	—	-1.35	-1.80	V
		T_a = 150 °C, I_{DR} = 31 A, V_{GS} = -5 V	—	-1.80	—	
Reverse recovery time	t_{rr}	I_{DR} = 33 A, V_{GS} = 0 V, V_{DD} = 800 V, -dI_{DR}/dt = 1000 A/μs	—	66	—	ns
Reverse recovery charge	Q_{rr}		—	594	—	nC
Peak reverse recovery current	I_{rr}		—	18	—	A

Note 3: Ensure that the channel temperature does not exceed 175 °C.

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7. Marking (Note)

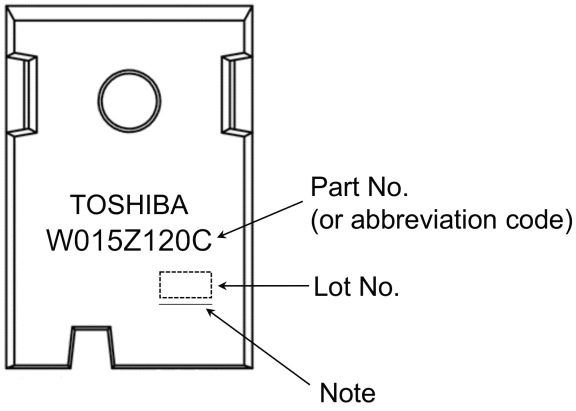


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.
Not underlined: [[Pb]]/INCLUDES > MCV
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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8. Characteristics Curves (Note)

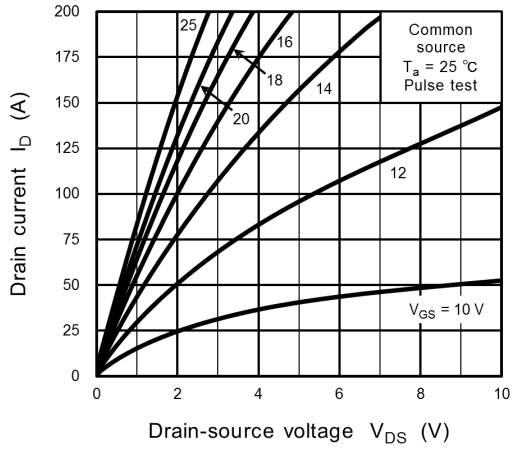


Fig. 8.1 I_D - V_{DS}

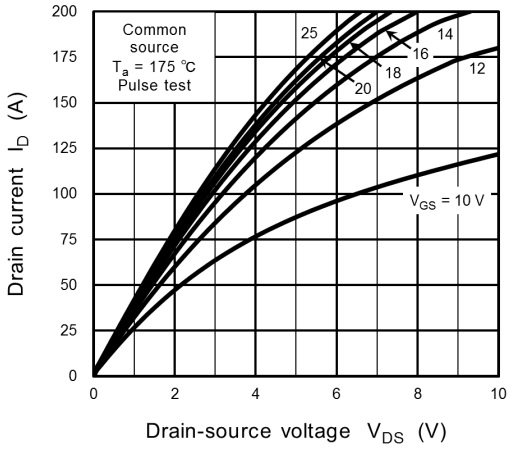


Fig. 8.2 I_D - V_{DS}

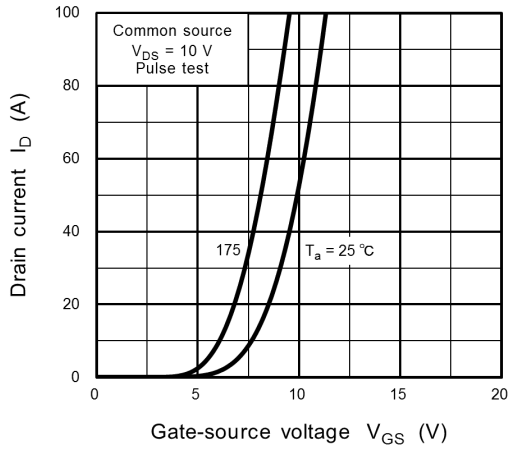


Fig. 8.3 I_D - V_{GS}

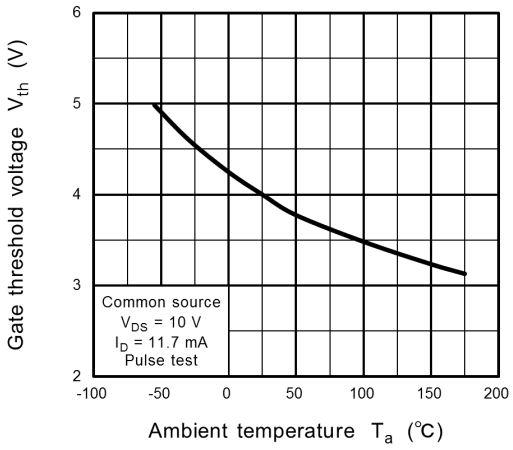


Fig. 8.4 V_{th} - T_a

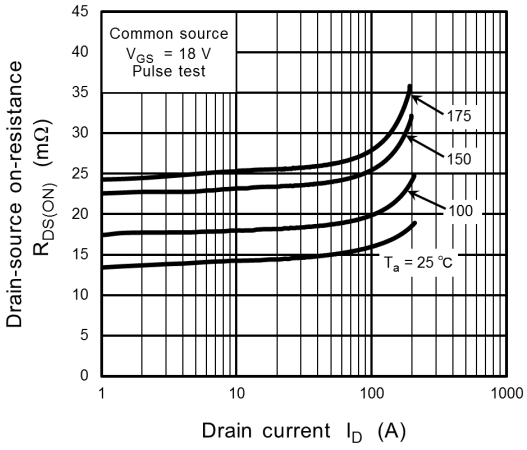


Fig. 8.5 $R_{DS(ON)}$ - I_D

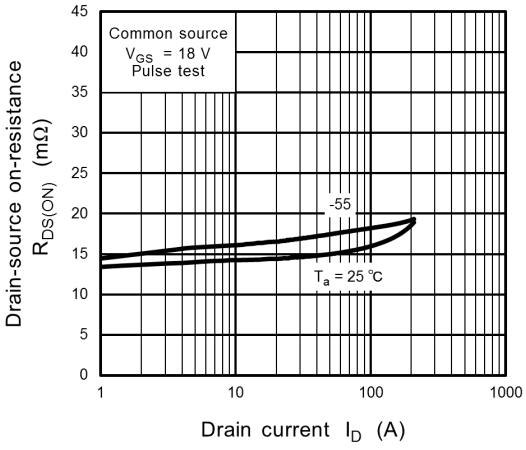


Fig. 8.6 $R_{DS(ON)}$ - I_D

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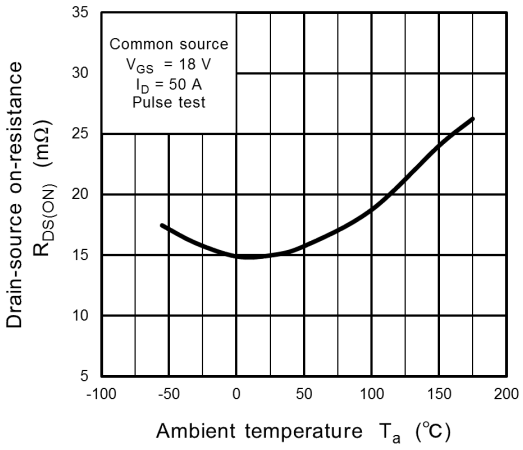


Fig. 8.7 $R_{DS(ON)}$ - T_a

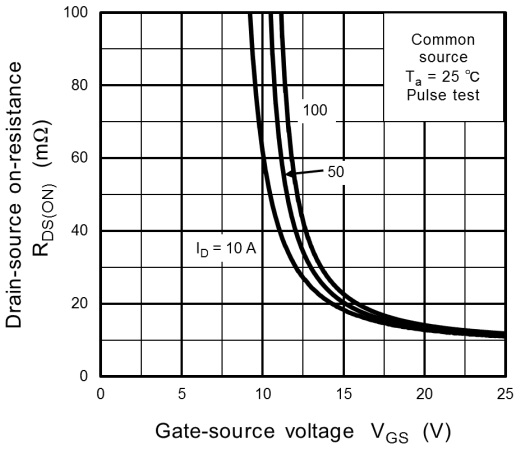


Fig. 8.8 $R_{DS(ON)}$ - V_{GS}

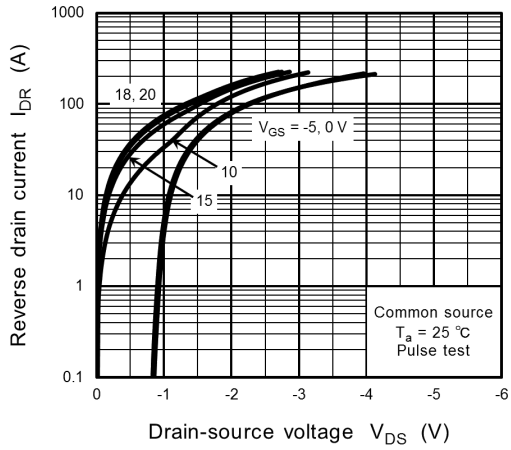


Fig. 8.9 I_{DR} - V_{DS}

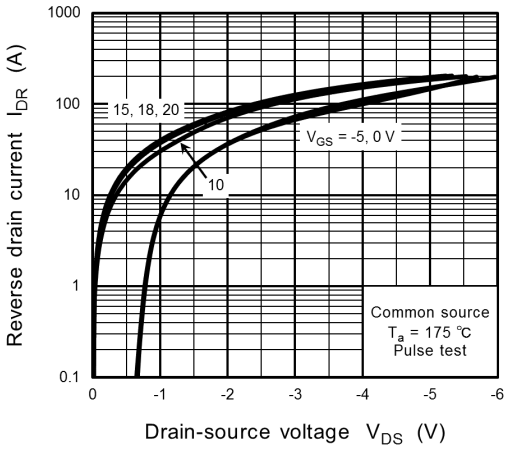


Fig. 8.10 I_{DR} - V_{DS}

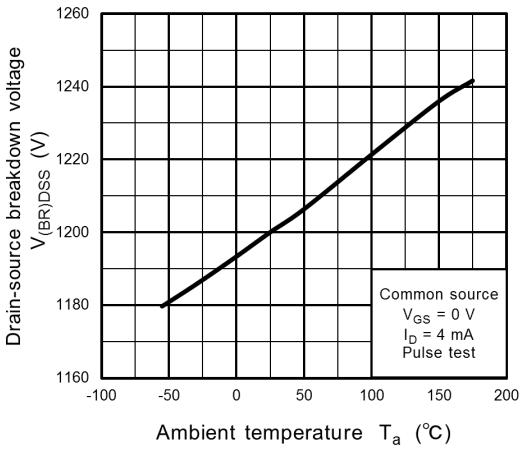


Fig. 8.11 $V_{(BR)DSS}$ - T_a

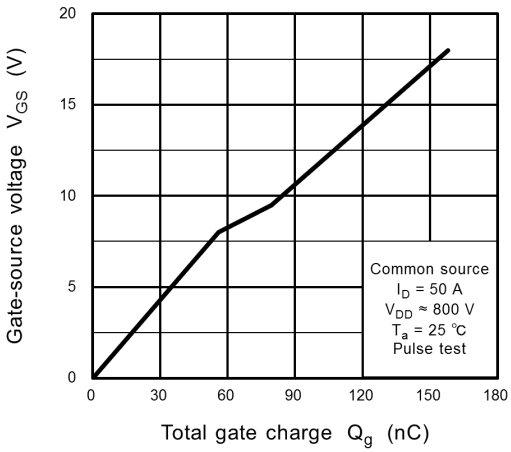


Fig. 8.12 Dynamic Input Characteristics

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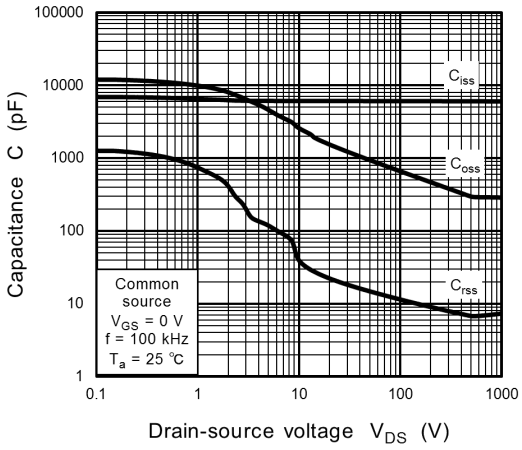


Fig. 8.13 C - V_{DS}

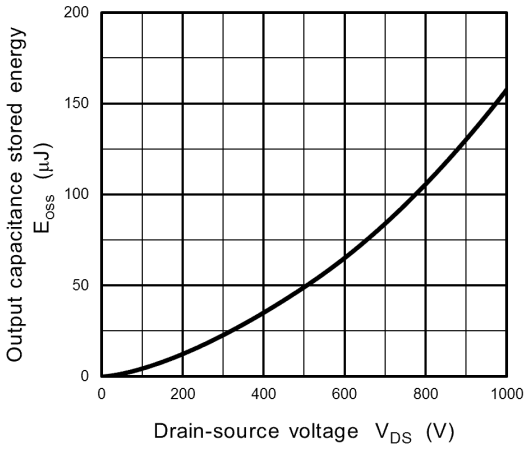


Fig. 8.14 E_{oss} - V_{DS}

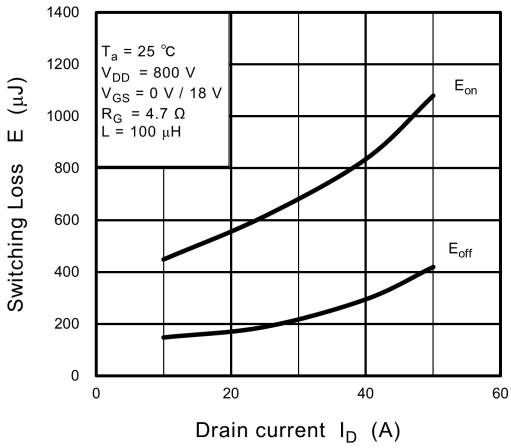


Fig. 8.15 E - I_D

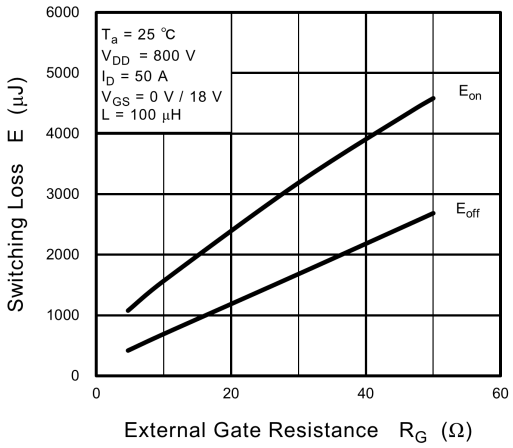


Fig. 8.16 E - R_G

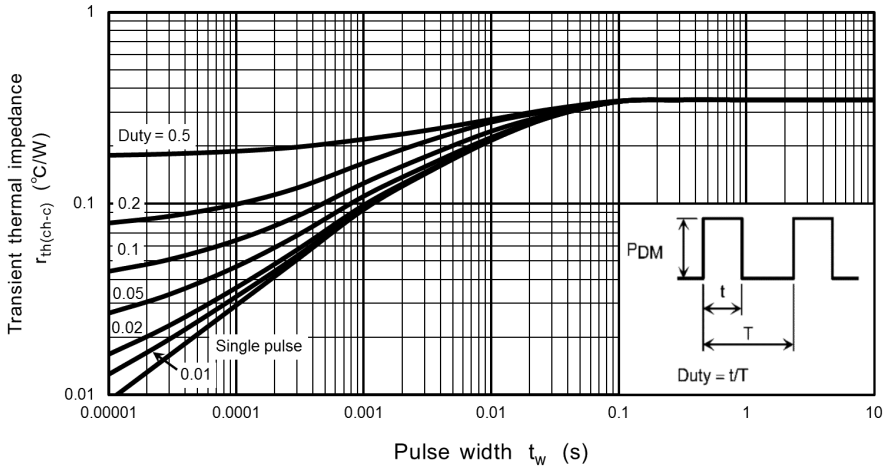


Fig. 8.17 r_{th} - t_w
(Guaranteed Maximum)

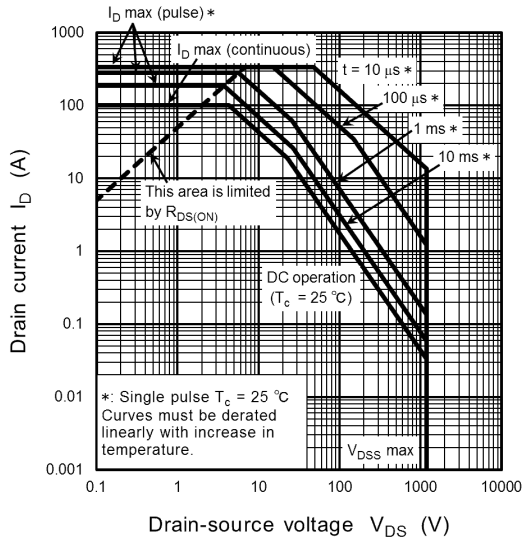


Fig. 8.18 Safe Operating Area (Guaranteed Maximum)

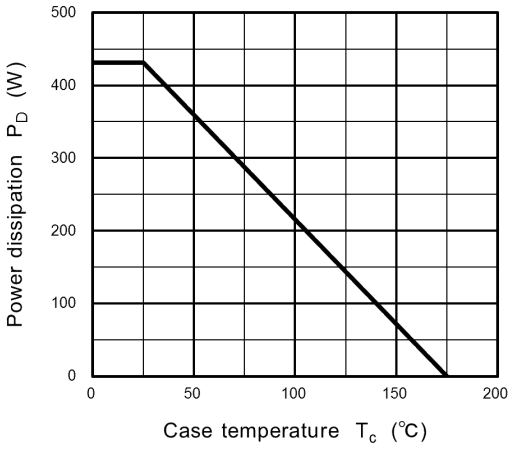
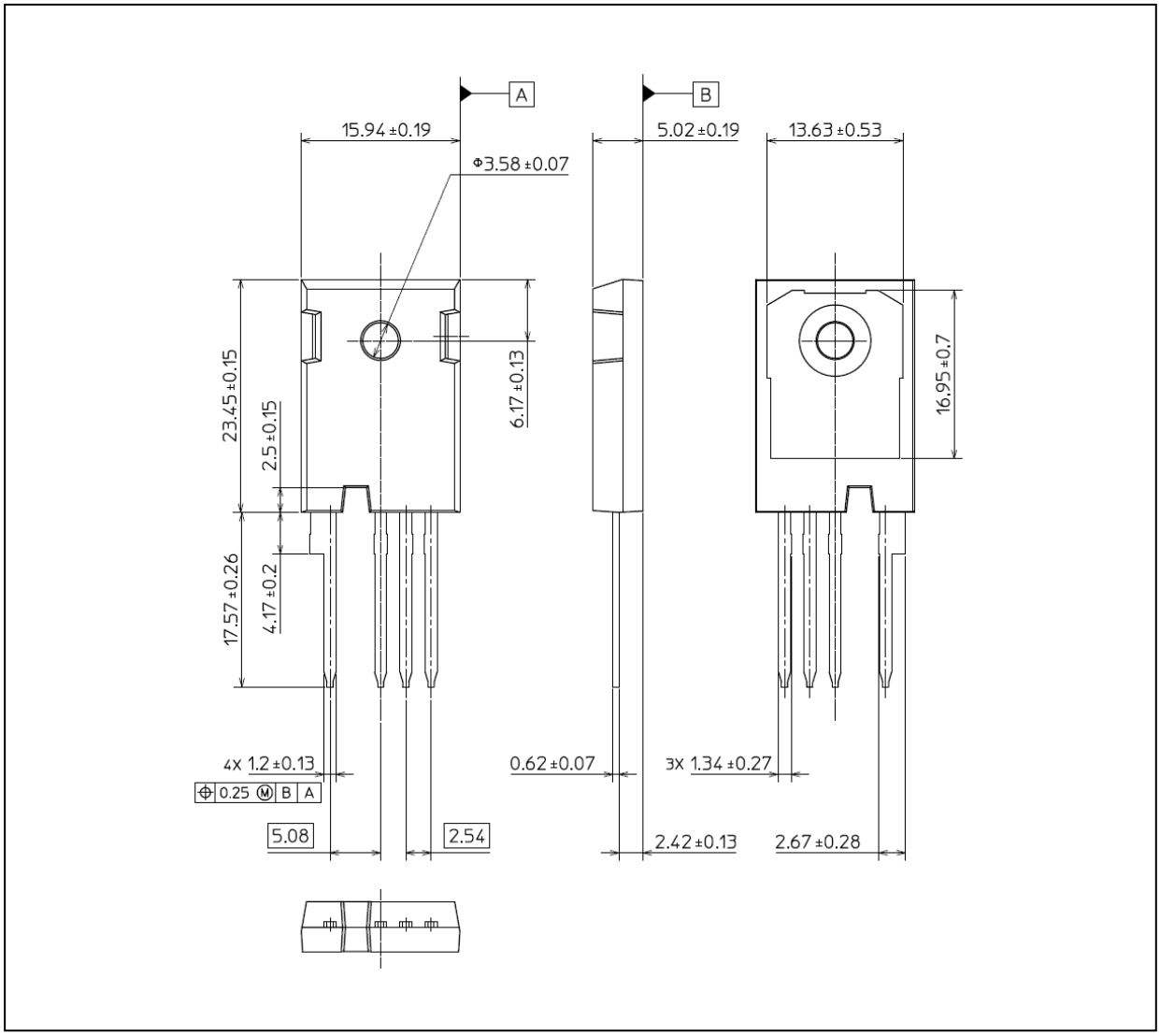


Fig. 8.19 P_D - T_c (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 6.55 g (typ.)

Package Name(s)
TOSHIBA: 2-16M3A
Nickname: TO-247-4L(X)

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